Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SC4604

Power Amplifier Application.

Power Switching Applications.

- Low collector-emitter saturation voltage: VCE (sat) = 0.5 V (max)
- High-speed switching:  $t_{stg} = 0.5 \mu s$  (typ.)
- Complementary to 2SA1761

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	80	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	6	V
Collector current	IC	3	Α
Base current	IB <	0.6	A
Collector power dissipation	Pc	900	⟨mW
Junction temperature	Tj(	150	,c
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

5.1 MAX.

0.75MAX.

0.8MAX.

0.6MAX.

1.0MAX.

0.6MAX.

1.27

1.27

2.5M

2.5M

2.5M

3. BASE

JEDEC TO-92MOD

JEITA —

TOSHIBA 2-5J1A

Weight: 0.36 g (typ.)

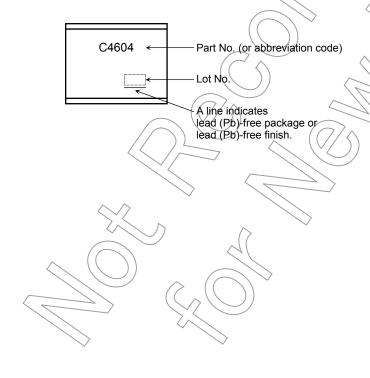
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



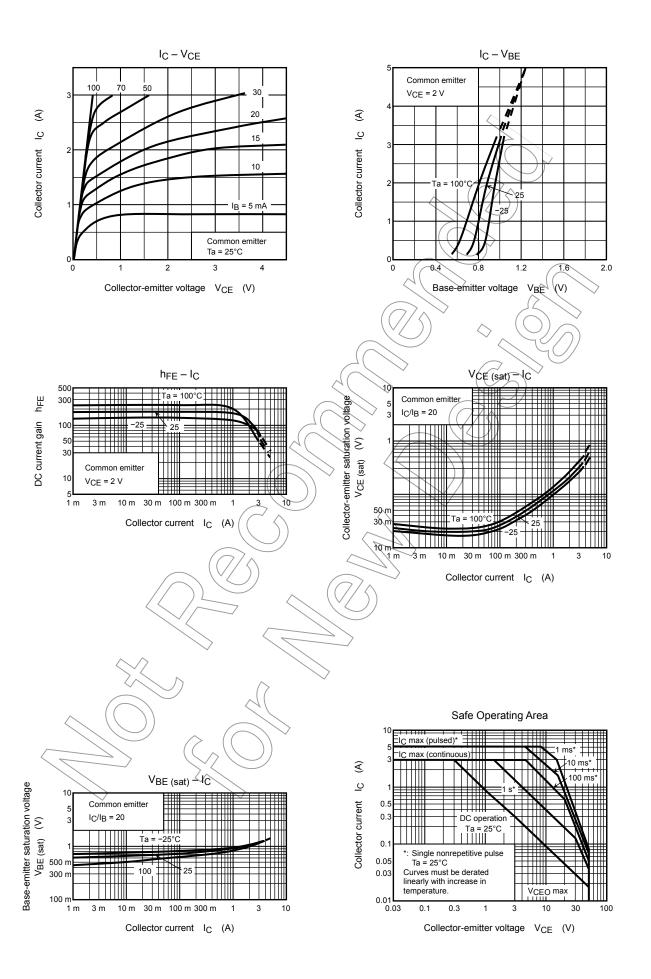
## Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 80 V, I <sub>E</sub> = 0	_	_	0.1	μΑ
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	_	_	0.1	μΑ
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>E</sub> = 0	50	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA	120 —	_	400	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A	40	) >-	-	
Collector-emitter	saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 75 mA	> <u>~</u>	_	0.5	V
Base-emitter satu	uration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 75 mA	$\bigcirc)$	_	1.2	V
Transition freque	ncy	f <sub>T</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA	_	100	-	MHz
Collector output of	capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	20	-	pF
Switching time	Turn-on time	ton	20 μs Input IB1 Output CC	- (	0.1	$\rightarrow$	
	Storage time	t <sub>stg</sub>			0.5	) –	μs
	Fall time	t <sub>f</sub>	30 V I <sub>B1</sub> = -I <sub>B2</sub> = 75 mA, duty cycle ≤ 1%		0.1	_	

## Marking



2 2006-11-10





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